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# GaAs MMIC Low Noise Amplifier for Micro Wave Application

# **HITACHI**

ADE-207-217 (Z) 1st. Edition July 1996

#### **Features**

- Suitable for low noise amplifier of PHS (1.9 GHz)
- Low voltage and low current operation (3V, 3mA typ.)
- Low noise (1.9 dB typ.)
- High power gain (13.5 dB typ.)
- Built–in input and output matching circuits (50 $\Omega$ )
- Small surface mount package (MPAK–5)

#### **Outline**

MPAK-5





# **Absolute Maximum Ratings** (Ta = 25°C)

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Item	Symbol	Ratings	Unit
Supply voltage	Vdd	5	V
Maximum current	ldd	6	mA
Power dissipation	Pd	100	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C
Operation temperature	Topr	-20 to +70	°C

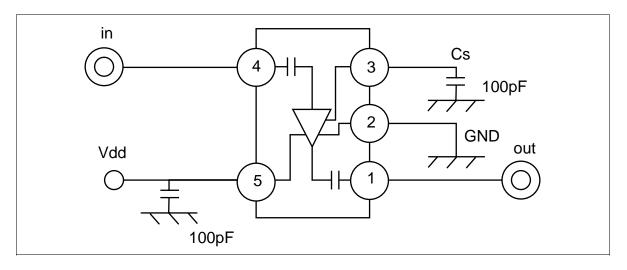
## **Electrical Characteristics** (Ta = 25°C, Vdd = 3V)

Item	Symbol	Min	Тур	Max	Unit	<b>Test Conditions</b>	Pin
Quiescent current	ldd	1.5	3	5.5	mA	No signal	
Power gain	PG	11.5	13.5	16	dB	f = 1.9 GHz	
Noise figure	NF	_	1.9	2.5	dB	f = 1.9 GHz	

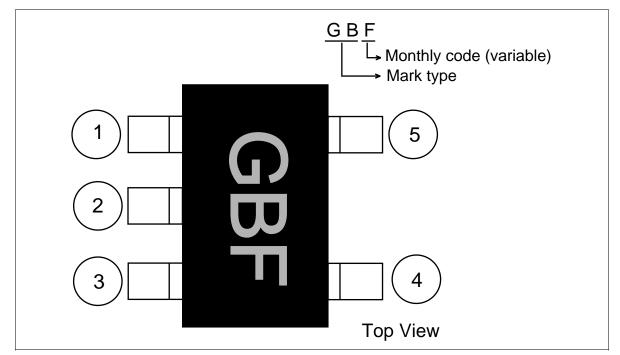
## **Typical Performance** (Ta = 25°C, Vdd = 3V)

Item	Symbol	Тур	Unit	Test Conditions	Pin
VSWR (input)	VSWR in	1.6	_	f = 1.9 GHz	4
VSWR (output)	VSWR out	1.6	_	f = 1.9 GHz	1
3rd order intermodulation distortion	IM3	58	dB	f = 1.9 GHz, UD = 1.9006 Ghz Pin = -30 dBm	

# **Block Diagram**

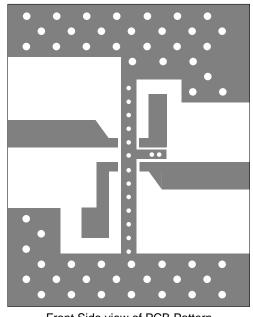


#### **Pin Arrangement**



Pin No.	Pin name	Function
1	RF out	RF output
2	GND	Ground
3	Cs	Bypath capacitor (>100 pF)
4	RF in	RF input
5	Vdd	Power supply

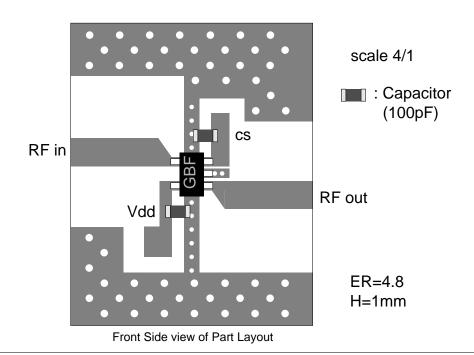
#### **Pattern Layout**



#### scale 4/1

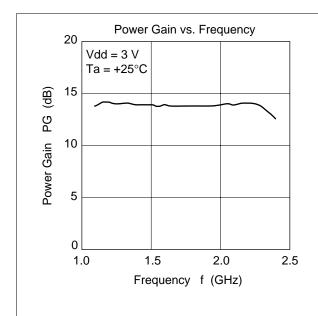
○ : \$0.5mm 。:φ0.3mm

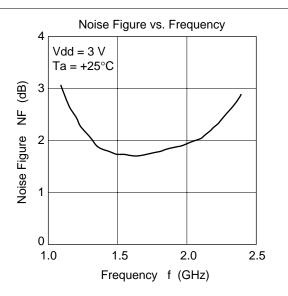
Front Side view of PCB Pattern

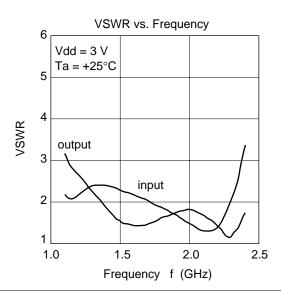


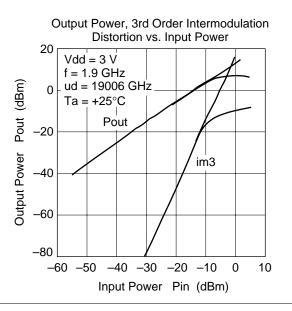
#### **Main Characteristics**

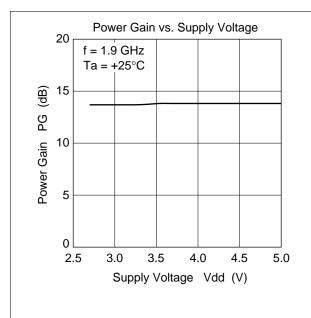
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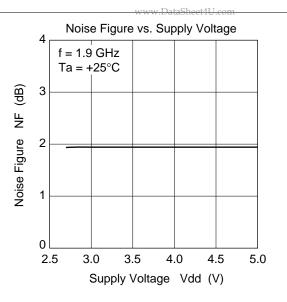


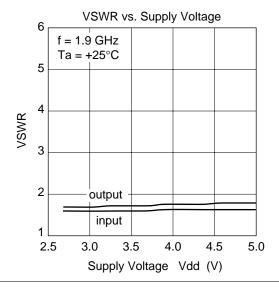


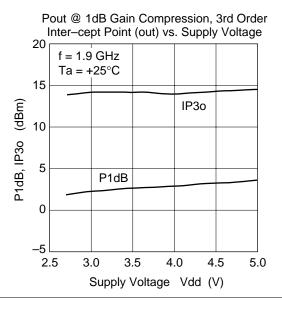


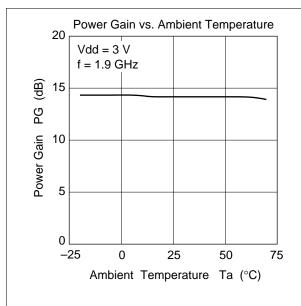


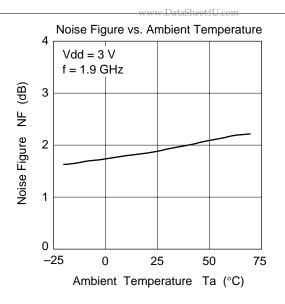


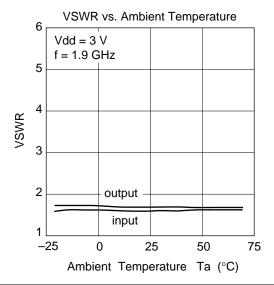


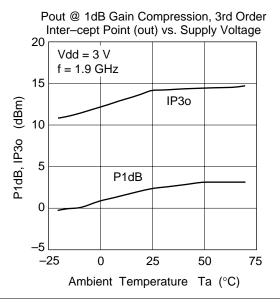


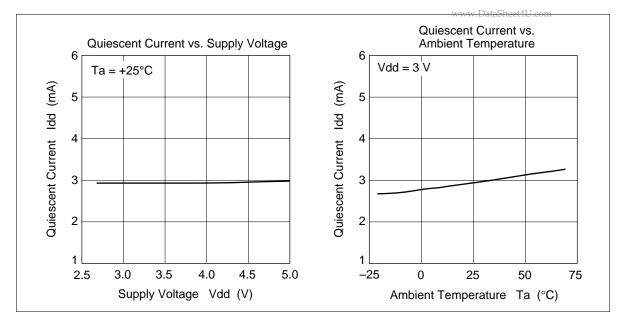






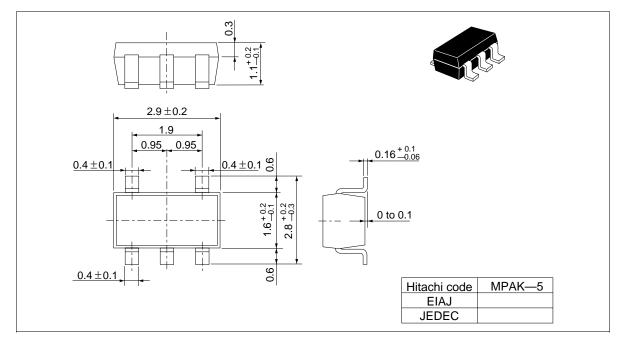






## **Package Dimentions**

Unit: mm



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